# Dual 2-Input Exclusive-OR Gate

# NL27WZ86

The NL27WZ86 is a high performance dual 2–input Exclusive–OR Gate operating from a 1.65 V to 5.5 V supply.

## Features

- Designed for 1.65 V to 5.5 V  $V_{CC}$  Operation
- 2.9 ns  $t_{PD}$  at  $V_{CC} = 5 V (typ)$
- Inputs/Outputs Overvoltage Tolerant up to 5.5 V
- IOFF Supports Partial Power Down Protection
- Source/Sink 24 mA at 3.0 V
- Available in US8, UDFN8 and UQFN8 Packages
- Chip Complexity < 100 FETs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Figure 1. Logic Symbol



## **ON Semiconductor®**

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US8

**US SUFFIX** 

**CASE 493** 

## MARKING DIAGRAMS









А

L

Y

W

Μ

UDFN8, 1.45x1.0 MU3 SUFFIX CASE 517BZ

## Х М 0

1



= Assembly Location
Lat Cada

- = Lot Code = Year Code
- = Week Code
- = Date Code
- = Pb-Free Package

## ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

## NL27WZ86



US8

UDFN8

Figure 2. Pinout

#### **PIN ASSIGNMENT** (US8 / UDFN8)

Pin	Function
1	A1
2	B1
3	Y2
4	GND
5	A2
6	B2
7	Y1
8	V <sub>CC</sub>

#### **PIN ASSIGNMENT** (UQFN8)

	-
Pin	Function
1	Y1
2	B2
3	A2
4	GND
5	Y2
6	B1
7	A1
8	V <sub>CC</sub>

#### FUNCTION TABLE

Inp	Output	
Α	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

H = HIGH Logic Level L = LOW Logic Level

#### MAXIMUM RATINGS

Symbol	Characteris	lics	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	NLV	−0.5 to +7.0 −0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage	NLV	−0.5 to +7.0 −0.5 to +6.5	V
V <sub>OUT</sub>	DC Output Voltage (NLV)	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +7.0 -0.5 to +7.0	V
	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +6.5 -0.5 to +6.5	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-50	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-50	mA
I <sub>OUT</sub>	DC Output Source/Sink Current		±50	mA
$I_{CC}$ or $I_{GND}$	DC Supply Current per Supply Pin or Ground	l Pin	±100	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 s	ecs	260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{JA}$	Thermal Resistance (Note 2)	US8 UQFN8 UDFN8	250 210 231	°C/W
PD	Power Dissipation in Still Air	US8 UQFN8 UDFN8	500 595 541	mW
MSL	Moisture Sensitivity		Level 1	-
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
$V_{ESD}$	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	V
I <sub>Latchup</sub>	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.

 Applicable to devices with outputs that hidy be in-stated.
Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22–A115–A (Machine Model) be discontinued per JEDEC/JEP172A. 4. Tested to EIA/JESD78 Class II.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Characteristics	Min	Мах	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	1.65	5.5	V
V <sub>IN</sub>	DC Input Voltage	0	5.5	V
V <sub>OUT</sub>	DC Output Voltage Active–Mode (High or Low Stat Tri–State Mode (Note Power–Down Mode (V <sub>CC</sub> = 0	1) 0	V <sub>CC</sub> 5.5 5.5	
T <sub>A</sub>	Operating Temperature Range	-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time $\begin{array}{c} V_{CC} = 1.65 \ V \ to \ 1.95 \\ V_{CC} = 2.3 \ V \ to \ 2.7 \\ V_{CC} = 3.0 \ V \ to \ 3.6 \\ V_{CC} = 4.5 \ V \ to \ 5.5 \end{array}$	V 0 V 0	20 20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

### DC ELECTRICAL CHARACTERISTICS

			V <sub>CC</sub>	T <sub>A</sub> = 25°C			–55°C ≤ T	A ≤ 125°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units
VIH	High-Level Input		1.65 to 1.95	0.65 V <sub>CC</sub>	-	_	0.65 V <sub>CC</sub>	-	V
	Voltage		2.3 to 5.5	0.70 V <sub>CC</sub>	-	-	0.70 V <sub>CC</sub>	-	
V <sub>IL</sub>	Low-Level Input		1.65 to 1.95	-	-	0.35 V <sub>CC</sub>	-	0.35 V <sub>CC</sub>	V
	Voltage		2.3 to 5.5	-	-	0.30 V <sub>CC</sub>	_	0.30 V <sub>CC</sub>	
V <sub>OH</sub>	High-Level Output Voltage		1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	V <sub>CC</sub> - 0.1 1.29 1.9 2.2 2.4 2.3 3.8	V <sub>CC</sub> 1.4 2.1 2.4 2.7 2.5 4.0		V <sub>CC</sub> - 0.1 1.29 1.9 2.2 2.4 2.3 3.8		V
V <sub>OL</sub>	Low-Level Output Voltage		1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	- - - - -	- 0.08 0.2 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55	- - - - - -	0.1 0.24 0.3 0.4 0.4 0.55 0.55	V
I <sub>IN</sub>	Input Leakage Current	$V_{IN} = 5.5 \text{ V or GND}$	1.65 to 5.5	-	-	±0.1	_	±1.0	μA
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	-	-	1.0	_	10	μA
I <sub>CC</sub>	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5	-	-	1.0	_	10	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### AC ELECTRICAL CHARACTERISTICS

				T <sub>A</sub> = 25°C		)	T <sub>A</sub> = -55	to 125°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Test Conditions	Min	Тур	Max	Min	Max	Units
t <sub>PLH</sub> ,	Propagation Delay,	1.65 to 1.95	C <sub>L</sub> = 15 pF	-	7.9	9.0	-	10.5	ns
t <sub>PHL</sub>	(A or B) to Y	2.3 to 2.7	R <sub>L</sub> = 1 MΩ R <sub>1</sub> = Open	-	4.1	7.0	-	7.5	
		3.0 to 3.6		-	3.0	4.8	-	5.2	
		4.5 to 5.5		-	2.2	3.5	-	3.8	
		3.0 to 3.6	$C_{L} = 50 \text{ pF},$	-	3.8	5.4	-	5.9	
		4.5 to 5.5	$R_L = 500 \Omega, R_1 = Open$	-	2.9	4.2	_	4.6	

#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC}$ = 5.5 V, $V_{IN}$ = 0 V or $V_{CC}$	2.5	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC}$ = 5.5 V, $V_{IN}$ = 0 V or $V_{CC}$	2.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	10 MHz, V <sub>CC</sub> = 3.3 V, V <sub>IN</sub> = 0 V or V <sub>CC</sub> 10 MHz, V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0 V or V <sub>CC</sub>	9 11	pF

5.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no–load dynamic power consumption;  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .



	t <sub>PLZ</sub> / t <sub>PZL</sub>	$2 \times V_{CC}$	50
	$t_{PHZ}$ / $t_{PZH}$	GND	50
⊥ c <sub>L*</sub>	X = Don't Car	e	

Test

t<sub>PLH</sub> / t<sub>PHL</sub>

Switch

Position

Open

 $R_L, \Omega$ 

500

500

 $C_L, pF$ 

See AC Characteristics Table

 $R_1, \Omega$ 

500

500

 $C_L$  includes probe and jig capacitance  $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega)$  f = 1 MHz

## Figure 3. Test Circuit





#### Figure 4. Switching Waveforms

		Vm		
V <sub>CC</sub> , V	V <sub>mi</sub> , V	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub> , t <sub>PZH</sub> , t <sub>PHZ</sub>	V <sub>Y</sub> , V
1.65 to 1.95	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.15
2.3 to 2.7	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.15
3.0 to 3.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3
4.5 to 5.5	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3

#### **DEVICE ORDERING INFORMATION**

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
NL27WZ86USG	US8	L8	Q4	3000 / Tape & Reel
NLV27WZ86USG*	US8	L8	Q4	3000 / Tape & Reel
NL27WZ86MQ1TCG	UQFN8, 1.6 x 1.6, 0.5P	AC	Q1	3000 / Tape & Reel
NL27WZ86MU1TCG (In Development)	UDFN8, 1.95 x 1.0, 0.5P	TBD	TBD	3000 / Tape & Reel
NL27WZ86MU3TCG (In Development)	UDFN8, 1.45 x 1.0, 0.35P	TBD	TBD	3000 / Tape & Reel
NL27WZ86MQT2CG (In Development)	UQFN8, 1.4 x 1.2, 0.4P	TBD	TBD	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

## Pin 1 Orientation in Tape and Reel







\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

\*This information is generic. Please refer to device data sheet for actual part marking.

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DIMENSIONS: MILLIMETERS

<sup>8X</sup> 0.53

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